

Current

11 A

### 600V N-Channel Super Junction MOSFET

Voltage

#### Features

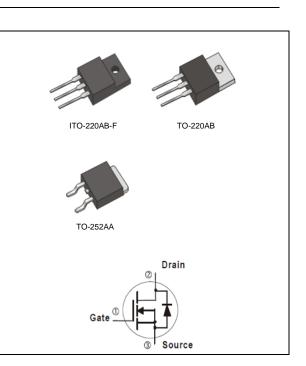
R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V, I<sub>D</sub>@3.8A<0.39Ω</li>

600 V

- Fast switching speed
- Low on-resistance
- Low Noise
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case : TO-252AA, TO-220AB, ITO-220AB-F
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams



#### **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	TO-252AA	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	600			- V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20				
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C		11			А	
Continuous Drain Current	$T_{C}=100^{\circ}C$		7.5				
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	22				
Power Dissipation (Note 3)	T <sub>C</sub> =25°C	P <sub>D</sub>	124	53	124	W	
	$T_{C}=100^{\circ}C$		0.99	0.424	0.99		
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C		1.5			A	
	T <sub>A</sub> =70°C	I <sub>D</sub>	1.2				
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2	1.04	2	W	
	T <sub>A</sub> =70°C		1.3	0.9	1.3		
Single Pulse Avalanche Energy (Note 5)		E <sub>AS</sub>	162			mJ	
Operating Junction and		T <sub>J</sub> ,T <sub>STG</sub>	-55~150			°C	
Storage Temperature Range							
Typical Thermal Resistance (Note 4,5)		$R_{ extsf{ heta}JC}$	1	2.36	1	°C/W	
		$R_{ extsf{ heta}JA}$	62.5	120	62.5	0/00	

• Limited only By Maximum Junction Temperature



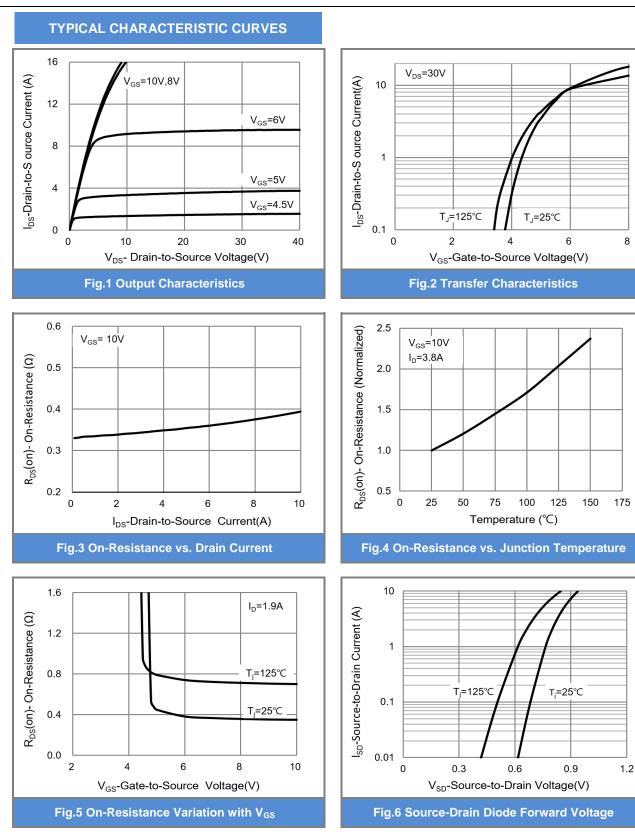
### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	600	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	2	3.1	4	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =3.8A	-	0.35	0.39	Ω
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =11A, V <sub>GS</sub> =0V	-	0.95	1.5	V
Transconductance	GFS	VDs=10V, ID=5.5A	-	6	-	S
Dynamic (Note 7)						
Total Gate Charge	Qg		-	32	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =300V, I <sub>D</sub> =11A, V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	4.6	-	
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V (100 - 50)	-	17	-	
Gate Input Resistance	R <sub>g</sub>	F = 1MHz	-	7.7	-	Ω
Input Capacitance	Ciss		-	531	-	pF
Output Capacitance	Coss	$V_{DS}=25V, V_{GS}=0V,$	-	547	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	69	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	12	-	ns
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =300V, $I_{D}$ =5.5A,	-	27	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$R_G=10\Omega^{(Note 2,3)}$	-	86	-	
Turn-Off Fall Time	t <sub>f</sub>		-	27	-	
Drain-Source Diode		·				
Maximum Continuous Drain-Source						
Diode Forward Current	I <sub>S</sub>		-	-	11	
Maximum Pulsed Drain-Source						A
Diode Forward Current	I <sub>SM</sub>		-	-	22	
Reverse Recovery Time	trr	V <sub>GS</sub> =0V, I <sub>S</sub> =11A	-	389	-	ns
Reverse Recovery Charge	Qrr	dI <sub>F</sub> / dt=100A/us <sup>(Note 2)</sup>	-	5.43	-	uC

Pulse width<u><</u>300us, Duty cycle<u><</u>2%.

- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. TO-252AA mounted on a 1 inch2 with 2oz.square pad of copper.
- 6. L=100mH,  $I_{AS}$ =1.8A,  $V_{DD}$ =50V,  $R_{G}$ =25 ohm, Starting  $T_{J}$ =25°C.
- 7. Guaranteed by design, not subject to production testing.







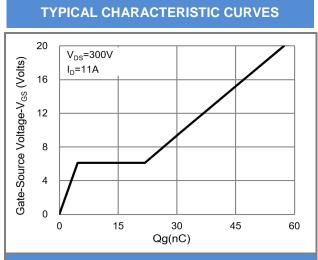


Fig.7 Gate-Charge Characteristics

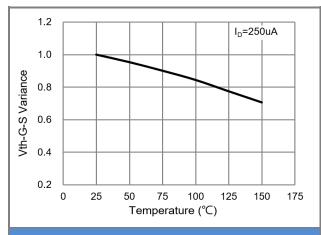
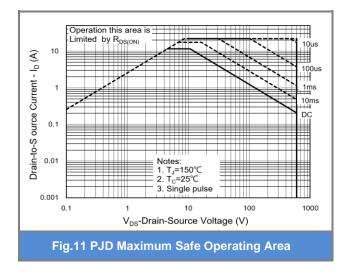
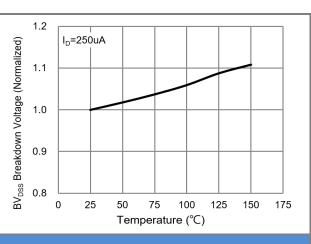
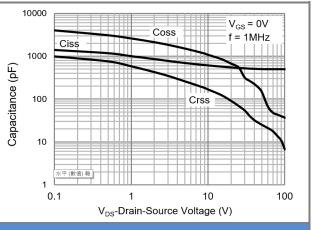


Fig.9 Threshold Voltage Variation with Temperature

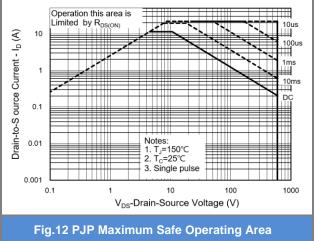




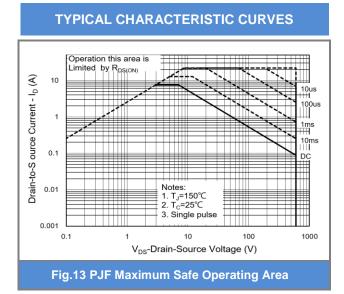












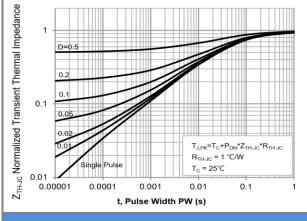
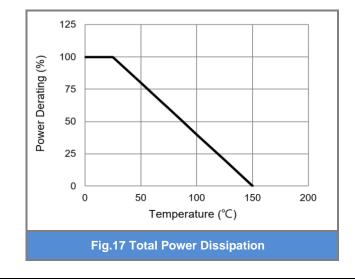


Fig.15 PJP Normalized Transient Thermal Impedance



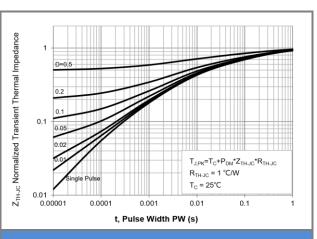


Fig.14 PJD Normalized Transient Thermal Impedance

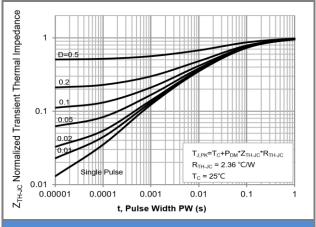
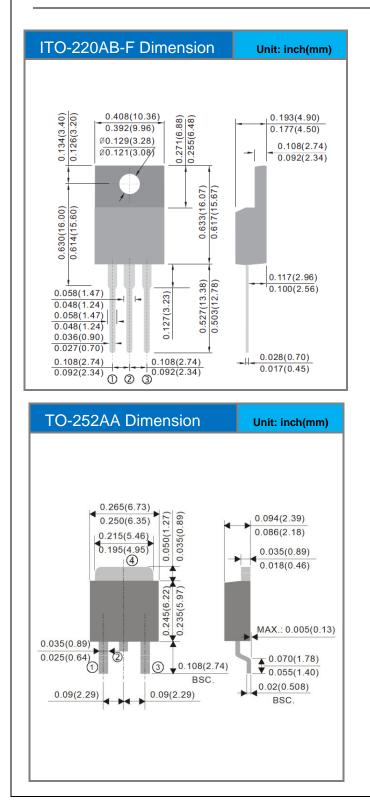
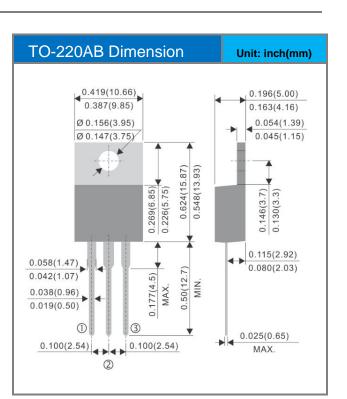


Fig.16 PJF Normalized Transient Thermal Impedance



#### **Packaging Information**











### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD60R390E_L2_00001	TO-252AA	3,000pcs / 13" reel	60R390E	Halogen free
PJP60R390E_T0_00001	TO-220AB	50pcs / Tube	60R390E	Halogen free
PJF60R390E_T0_00001	ITO-220AB-F	50pcs / Tube	60R390E	Halogen free





### Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Panjit: <u>PJD60R390E\_L2\_00001</u>